

REFERENCE

SHARP

SPEC.No. ED-09G003  
ISSUE July 23, 2009

SYSTEM DEVICE DIVISION I  
ELECTRONIC COMPONENTS AND DEVICES GROUP  
SHARP CORPORATION

SPECIFICATION

DEVICE SPECIFICATION FOR  
PHOTOINTERRUPTER  
MODEL No. GP1A30R1J00F

Specified for

Enclosed please find copies of the Specifications which consists of 13 pages including cover.  
This specification sheets and attached sheets shall be both side copy.  
After confirmation of the contents, please be sure to send back  copies of the Specifications  
with approving signature on each.

CUSTOMER'S APPROVAL

PRESENTED

DATE

DATE

\_\_\_\_\_

\_\_\_\_\_

BY

BY



\_\_\_\_\_

\_\_\_\_\_

M. Kubo,  
Department General Manager of  
Development Dept. IV  
System Device Division I  
Electronic Components and Devices Group  
SHARP CORPORATION

# REFERENCE

Product name : PHOTOINTERRUPTER

Model No. : GP1A30R1J00F

1. These specification sheets include materials protected under copyright of Sharp Corporation ("Sharp"). Please do not reproduce or cause anyone to reproduce them without Sharp's consent.
2. When using this product, please observe the absolute maximum ratings and the instructions for use outlined in these specification sheets, as well as the precautions mentioned below. Sharp assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets, and the precautions mentioned below.

(Precautions)

- (1) This product is designed for use in the following application areas ;

|   |   |   |
|---|---|---|
| { | <ul style="list-style-type: none"> <li>• OA equipment    • Audio visual equipment    • Home appliances</li> <li>• Telecommunication equipment (Terminal)    • Measuring equipment</li> <li>• Tooling machines    • Computers</li> </ul> | } |
|---|---|---|

If the use of the product in the above application areas is for equipment listed in paragraphs (2) or (3), please be sure to observe the precautions given in those respective paragraphs.

- (2) Appropriate measures, such as fail-safe design and redundant design considering the safety design of the overall system and equipment, should be taken to ensure reliability and safety when this product is used for equipment which demands high reliability and safety in function and precision, such as ;

|   |   |   |
|---|---|---|
| { | <ul style="list-style-type: none"> <li>• Transportation control and safety equipment (aircraft, train, automobile etc.)</li> <li>• Traffic signals    • Gas leakage sensor breakers    • Rescue and security equipment</li> <li>• Other safety equipment</li> </ul> | } |
|---|---|---|

- (3) Please do not use this product for equipment which require extremely high reliability and safety in function and precision, such as ;

|   |  |   |
|---|--|---|
| { | <ul style="list-style-type: none"> <li>• Space equipment    • Telecommunication equipment (for trunk lines)</li> <li>• Nuclear power control equipment    • Medical equipment</li> </ul> | } |
|---|--|---|

- (4) Please contact and consult with a Sharp sales representative if there are any questions regarding interpretation of the above three paragraphs.

3. Please contact and consult with a Sharp sales representative for any questions about this product.

## 1. Application

This specification applies to the outline and characteristics of transmissive type photointerrupter, Model No. GP1A30R1J00F.

REFERENCE

## 2. Outline

Refer to the attached drawing No. CY14652i02. Page 4.

## 3. Ratings and characteristics

- Refer to the attached sheet, Page 5 to 8.
- Resolution : Disk slit pitch = 0.704mm
- Output waveform : Digital 2-phase (Phase A and Phase B)

## 4. Reliability

Refer to the attached sheet, Page 9.

## 5. Outgoing inspection

Refer to the attached sheet, Page 10.

## 6. Supplements

## 6.1 Parts

Refer to the attached sheet, Page 11.

## 6.2 Packing

Refer to the attached drawing No. CY14654i09, Page 12.

## 6.3 ODS materials

This product shall not contain the following materials.

Also, the following materials shall not be used in the production process for this product.

Materials for ODS : CFC<sub>s</sub>, Halon, Carbon tetrachloride, 1.1.1-Trichloroethane (Methyl chloroform)

## 6.4 Specified brominated flame retardants

Specified brominated flame retardants (PBB and PBDE) are not used in this device at all.

## 6.5 Compliance with each regulation

## 6.5.1 The RoHS directive(2002/95/EC)

This product complies with the RoHS directive(2002/95/EC)

Object substances: mercury,lead, cadmium,hexavalent chromium,polybrominated biphenyls (PBB)  
and polybrominated diphenyl ethers (PBDE)

## 6.5.2 Content of six substances specified in Management Method for Control of Pollution Caused by Electronic Information Products Regulation (Chinese : 电子信息产品污染控制管理办法).

| Category         | Toxic and hazardous substances |              |              |   |                                |                                       |
|------------------|--------------------------------|--------------|--------------|---|--------------------------------|---------------------------------------|
|                  | Lead (Pb)                      | Mercury (Hg) | Cadmium (Cd) | Hexavalent chromium (Cr <sup>6+</sup> ) | Polybrominated biphenyls (PBB) | Polybrominated diphenyl ethers (PBDE) |
| Photointerrupter | ✓                              | ✓            | ✓            | ✓                                       | ✓                              | ✓                                     |

✓ : indicates that the content of the toxic and hazardous substance in all the homogeneous materials of the part is below the concentration limit requirement as described in SJ/T 11363-2006 standard.

## 6.6 Product mass : Approximately 0.8g

## 6.7 Country of origin : Japan, China, Indonesia

# REFERENCE

## 7. Notes

### 7.1 The recommendation conditions of forward current:

This product is designed in consideration of using this product under the condition of typical  $I_F=30\text{mA}$  as a standard.

### 7.2 In order to stabilize power supply line, it is recommended to have a by-pass capacitor of $0.01\mu\text{F}$ or more between $V_{cc}$ and GND near the device.

### 7.3 When tightening this product with the screw, please use the M2 machine screw in combination with the washer.

The recommended tightening torque is  $0.2$  to  $0.3\text{ N} \cdot \text{m}$ .

However, this recommended tightening torque is the reference value because the tightening torque varies according to the screw and the bolted joint.

Before tightening the screw, please certainly confirm the tightening strength of this product and the object on which this product is mounted. Also, when tightening the screw with the tools such as the screw-driver, if the pushing force by the screw-driver is too strong, the damage of the product performances such as the break of the holder's mounting hole may be caused by the application of the external force.

Therefore, please be careful not to apply such a force to this product.

### 7.4 Cleaning conditions :

- (1) Solvent cleaning : Solvent temperature  $45^\circ\text{C}$  or less  
Immersion 3 min. or less
- (2) Ultrasonic cleaning : The effect to device by ultrasonic cleaning differs by cleaning bath size, ultrasonic power output, cleaning time, PCB size or device mounting condition etc.  
Please test it in actual using condition and confirm that doesn't occur any defect before starting the ultrasonic cleaning.
- (3) Applicable solvent : Ethyl alcohol, Methyl alcohol, Isopropyl alcohol

### 7.5 Soldering

To solder onto lead pins, solder at  $260^\circ\text{C}$  for 5 seconds or less.

Please take care not to let any external force exert on lead pins when soldering or just after soldering.

Please don't do soldering with preheating, and please don't do soldering by reflow.

### 7.6 OPIC chip due to micro design is easily affected by the Electro static discharge.

At operating, in order to prevent the destruction and the defect of characteristics by Electro static discharge, please take a general countermeasure of the Electro static discharge.

### 7.7 Storage and usage environment

Polycarbonate is used as the case material of this product.

If polycarbonate contacts with the hot liquid and the alkaline solution (alkaline atmosphere), polycarbonate is hydrolyzed. Therefore, please do not store and use this product in such an environment.

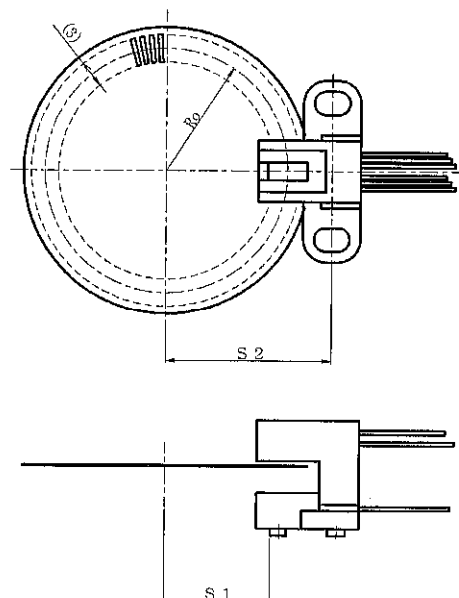
### 7.8 Disk design for GP1A30R1J00F

Given the disk resolution (N),  $R_o$ (distance between the disk center and half of a slit) and  $S_1, S_2$  (installing position of encoder) will be provided by the following equations.

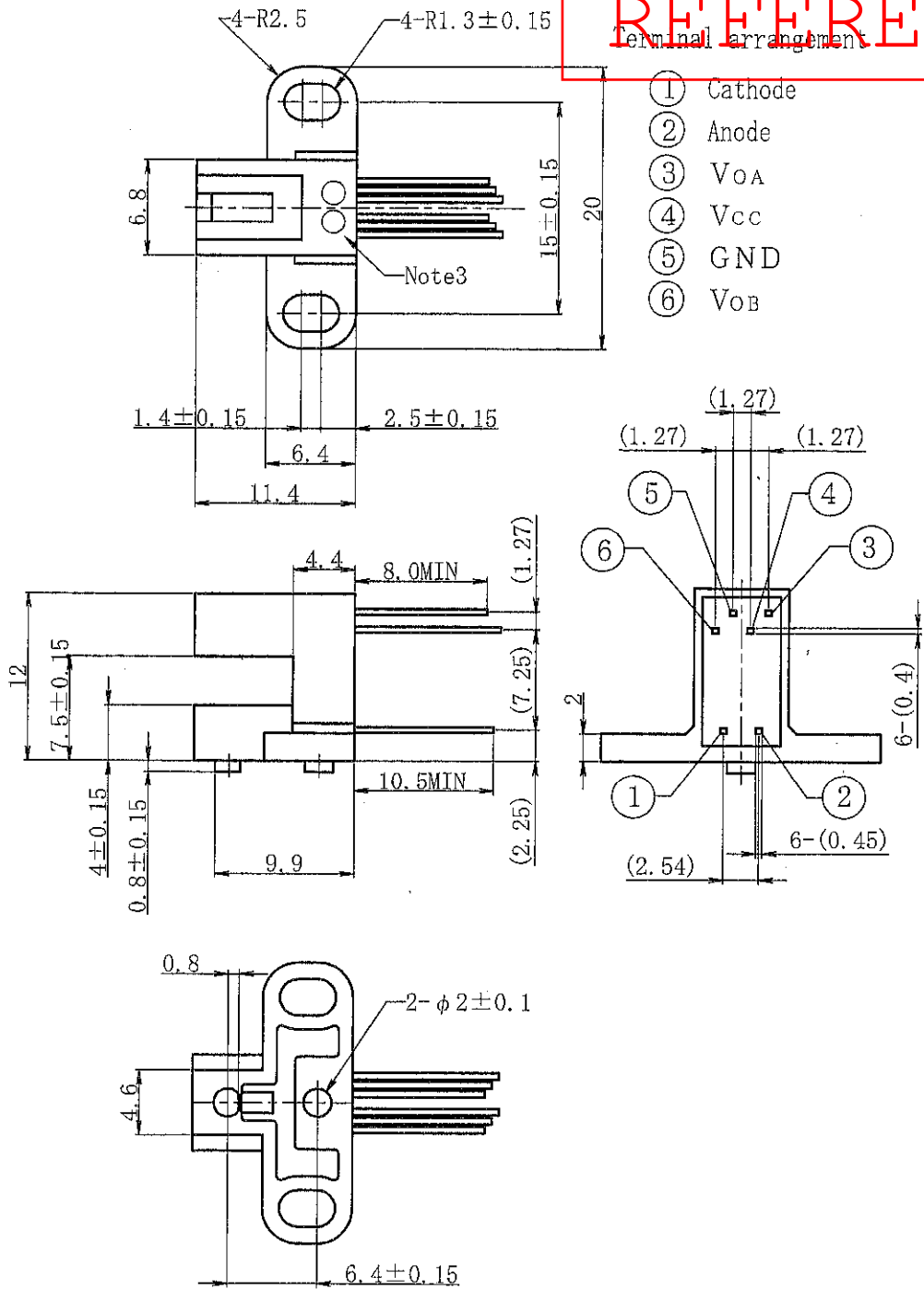
$$R_o = N / 120 \times 13.45 \text{ (Unit : mm)}$$

$$S_1 = R_o - 1.765 \text{ (Unit : mm)}$$

$$S_2 = S_1 + 6.7 \text{ (Unit : mm)}$$



REFERENCE

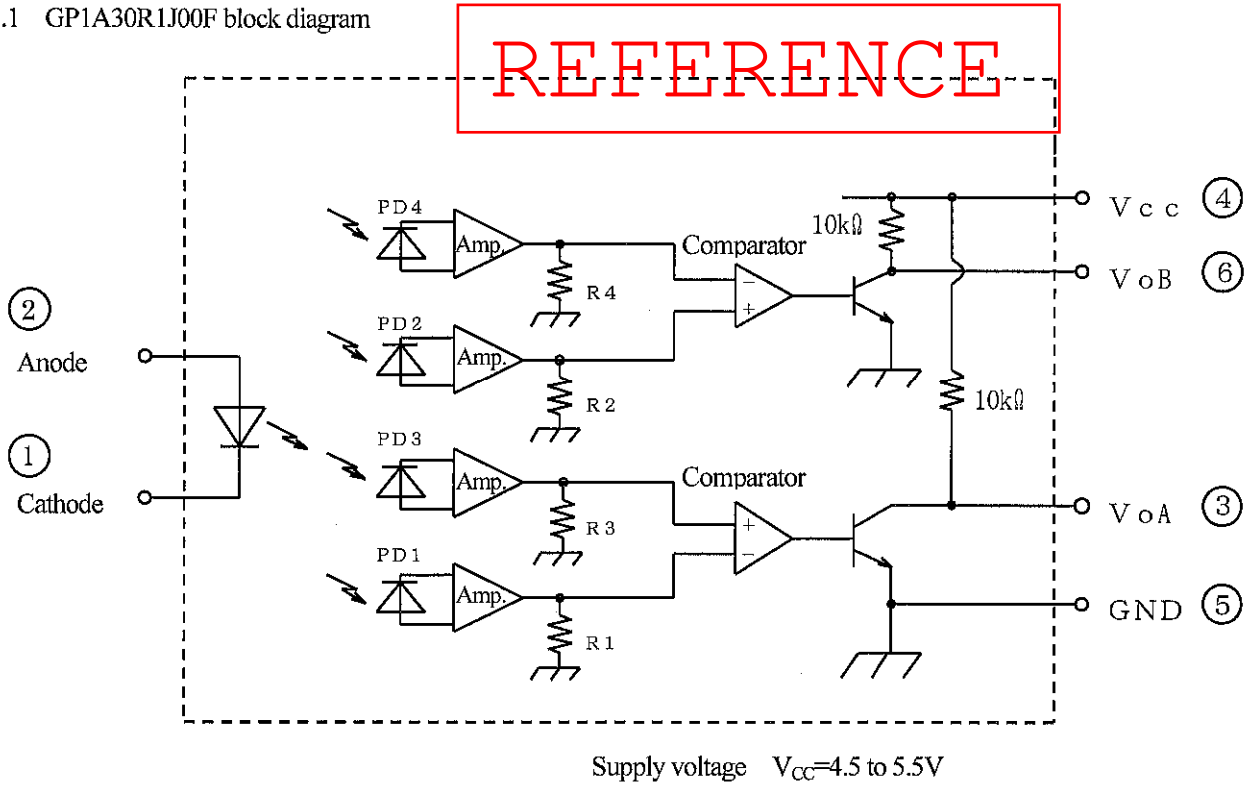


Note

- 1) Unspecified tolerances shall be ±0.2.
- 2) Dimensions in parenthesis are shown for reference.
- 3) Date code shall be displayed in 2 digits.

3. Ratings and characteristics

3.1 GP1A30R1J00F block diagram



3.2 Absolute maximum ratings

T<sub>a</sub>=25°C

| Parameter                |                          | Symbol            | Rating     | Unit |
|--------------------------|--------------------------|-------------------|------------|------|
| Input                    | Forward current *1       | I <sub>F</sub>    | 50         | mA   |
|                          | Reverse voltage          | V <sub>R</sub>    | 6          | V    |
| Output                   | Supply voltage           | V <sub>cc</sub>   | 7          | V    |
|                          | Low level output current | I <sub>O(L)</sub> | 20         | mA   |
|                          | Power dissipation *1     | P <sub>o</sub>    | 250        | mW   |
| Operating temperature    |                          | T <sub>opr</sub>  | 0 to +70   | °C   |
| Storage temperature      |                          | T <sub>stg</sub>  | -40 to +80 | °C   |
| Soldering temperature *2 |                          | T <sub>sol</sub>  | 260        | °C   |

\*1 The derating factors of absolute maximum ratings due to ambient temperature are shown in Fig. 1, 2.

\*2 Soldering time : 5s or less

REFERENCE

3.3 Electro-optical characteristics

Ta=25°C

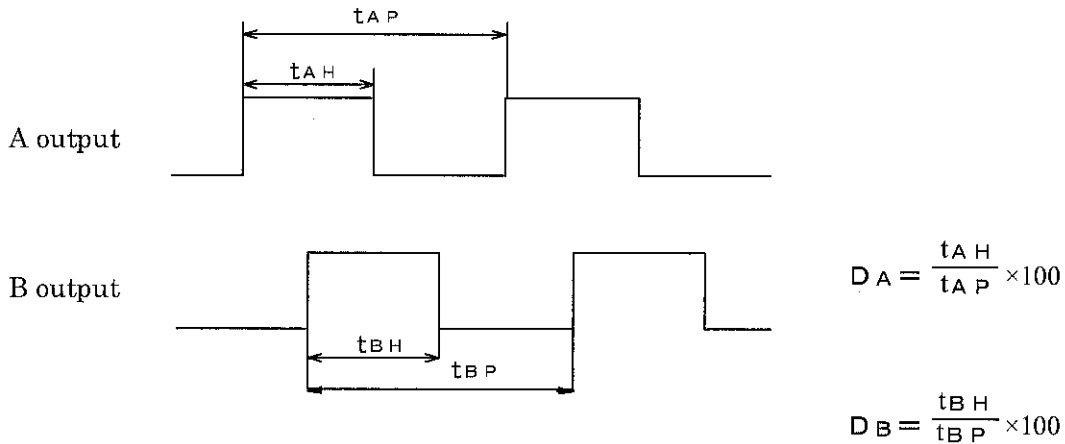
| Parameter                   |                                | Symbol           | Conditions  | MIN.                                      | TYP. | MAX. | Unit |
|-----------------------------|--------------------------------|------------------|---|---|------|------|------|
| Input                       | Forward voltage                | V <sub>F</sub>   | I <sub>F</sub> =30mA  | -   | 1.2  | 1.5  | V    |
|                             | Reverse current                | I <sub>R</sub>   | V <sub>R</sub> =3V  | -   | -    | 10   | μA   |
| Output                      | Operating supply voltage range | V <sub>CC</sub>  | -   | 4.5                                       | 5.0  | 5.5  | V    |
|                             | Low level output voltage       | V <sub>OL</sub>  | V <sub>CC</sub> =5V, I <sub>F</sub> =30mA<br>I <sub>OL</sub> =8mA             | -   | 0.1  | 0.4  | V    |
|                             | High level output voltage      | V <sub>OH</sub>  | V <sub>CC</sub> =5V, I <sub>F</sub> =30mA                                     | 2.4                                       | 4.9  | -    | V    |
|                             | Supply current                 | I <sub>CC</sub>  | V <sub>CC</sub> =5V, I <sub>F</sub> =30mA<br>Phases A and B both at low level | -   | 5    | 20   | mA   |
| Transfer characteristics ※1 | Duty                           | D <sub>A</sub>   | V <sub>CC</sub> =5V<br>I <sub>F</sub> =30mA<br>f=2.5kHz                       | 20  | 50   | 80   | %    |
|                             |                                | D <sub>B</sub>   |   |   |      |      |      |
|                             | Response frequency             | f <sub>max</sub> |   | V <sub>CC</sub> =5V, I <sub>F</sub> =30mA | -    | -    | 10   |

※1 The test condition is according to Fig.3 (CY14653i06)  
Transfer characteristics value does not include any error of disk slit.

Note: It is recommended that the GP1A30R1J00F be used under the condition of typical I<sub>F</sub>=30mA for which it is designed.

3.4 Output waveform

Disk rotational direction: Counterclockwise when seen from the detector side.



Disk rotational direction: Clockwise when seen from the detector side.

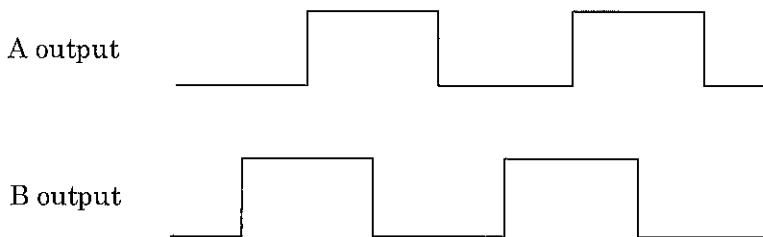


Fig.1 Forward current vs. ambient temperature

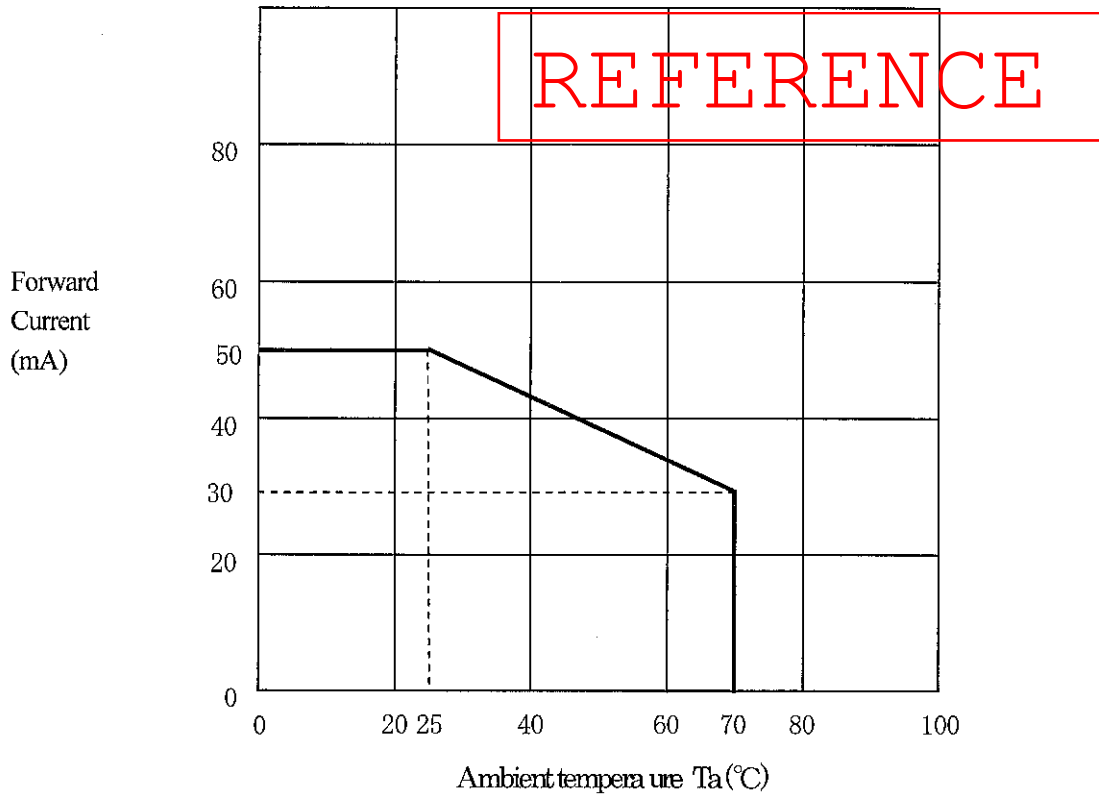


Fig.2 Output power dissipation vs. ambient temperature

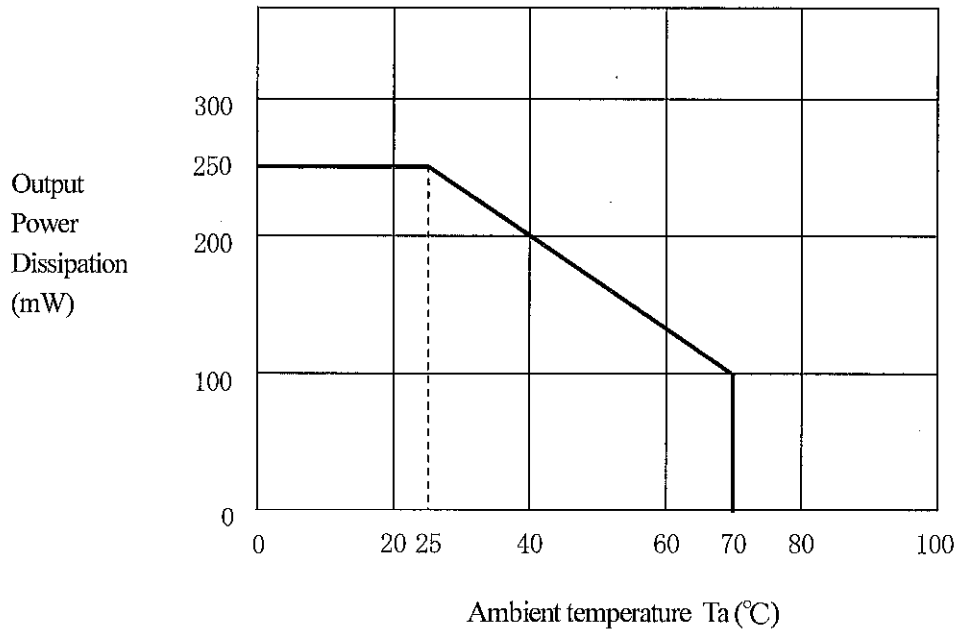
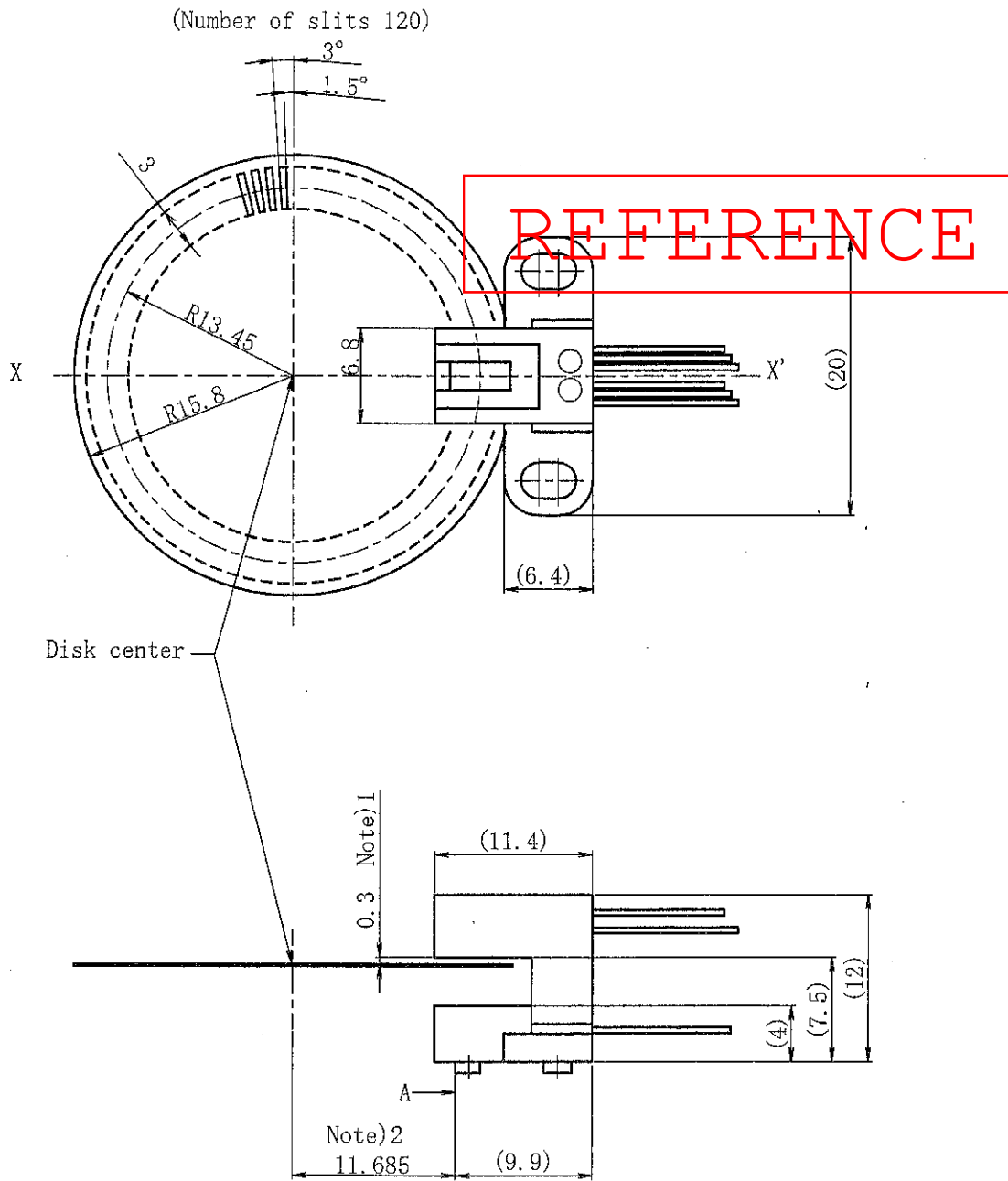




Fig.3 GP1A30R1J00F Test Condition (Drawing No.CY14653i06)

Scale : Free

Unit : 1/1mm



Note

- 1) Distance between disk surface and case surface in the detector side is 0.3mm.
- 2) Encoder positioning pin is positioned on X-X' axis. Distance between center of disk and portion A of positioning pin is 11.685mm.
- 3) Center of disk slit is R13.45mm.

## 4. Reliability

The reliability of products shall satisfy items listed below.

Confidence level : 90%

LTPD : 10 or 20

| Test Items                           | Test Conditions   | Failure Judgement Criteria                       | Samples (n)   |
|--------------------------------------|---|--|---------------|
|                                      |   |  | Defective (c) |
| Temperature cycling                  | 1 cycle -40°C to +80°C<br>(30min) (30min)<br>20 cycles test                   | $V_F \geq U \times 1.2$                          | n=22, c=0     |
| High temp. and high humidity storage | +60°C, 90%RH, 500h  | $I_R \geq U \times 2$                            | n=22, c=0     |
| High temp. storage                   | +80°C, 500h   | $V_{OL} \geq U \times 1.2$                       | n=22, c=0     |
| Low temp. storage                    | -40°C, 500h   | $V_{OH} \leq L \times 0.8$                       | n=22, c=0     |
| Operation life                       | $I_F=30mA, V_{CC}=5V, T_a=25^\circ C, 500h$                                   | $I_{CC} \geq U \times 1.2$                       | n=22, c=0     |
| Mechanical shock                     | 15000m/s <sup>2</sup> , 0.5ms<br>3 times/±X, ±Y, ±Z direction                 | Duty : Shall be within the specification values. | n=11, c=0     |
| Variable frequency vibration         | 100 to 2000 to 100Hz/4min<br>4 times/X, Y, Z direction<br>200m/s <sup>2</sup> |  | n=11, c=0     |
| Terminal strength (Tension)          | Weight: 5N<br>30s/each terminal   |  | n=11, c=0     |
| Terminal strength (Bending)          | Weight: 5N<br>0° →90° →0° →-90° →0°<br>1time bending                          |  | n=11, c=0     |
| Soldering heat                       | 260°C, 5s   | L: Lower specification limit                     | n=11, c=0     |
| Solderability                        | 245 ±3°C, 5s  | *1   | n=11, c=0     |

\* Test conditions shall be based upon the specification.

\*1 Solder shall adhere at less than 95% area of immersed portion of lead.

The alloy composition of solder used for lead free should be Sn-3.0Ag-0.5Cu.

Flux used for precleaning should be equivalent to EC-19S-8(TAMURA KAKEN CORPORATION).

## 5. Outgoing inspection

## 5.1 Inspection items

- (1) Electrical characteristic  
 $V_F$ ,  $I_R$ ,  $V_{OL}$ ,  $V_{OH}$ ,  $I_{CC}$ , Duty
- (2) Appearance

REFERENCE

## 5.2 Sampling method and Inspection level

A single sampling plan, normal inspection level II based on ISO 2859 is applied.

The AQL according to the inspection items are shown below.

| Defect       | Inspection item   | AQL   |
|--------------|---|-------|
| Major defect | Electrical characteristics defect<br>Unreadable marking | 0.1%  |
| Minor defect | Appearance defect except the above mentioned            | 0.25% |

## 6. Supplements

## 6.1 Parts

This product uses the below parts.

## 6.1.1 Light detector (Quantity : 1)

(Using a silicon photodiode as light detecting portion, and a bipolar IC as signal processing circuit.)

| Type       | Maximum sensitivity wavelength (nm) | Sensitivity wavelength (nm) | Response time ( $\mu$ s) |
|------------|-------------------------------------|-----------------------------|--------------------------|
| Photodiode | 900                                 | 400 to 1200                 | 100                      |

REFERENCE

## 6.1.2 Light emitter (Quantity : 1)

| Type   | Material | Maximum light emitting wavelength (nm) |
|--|----------|--|
| Infrared light emitting diode (Non-coherent) | GaAlAs   | 940                                    |

## 6.1.3 Material

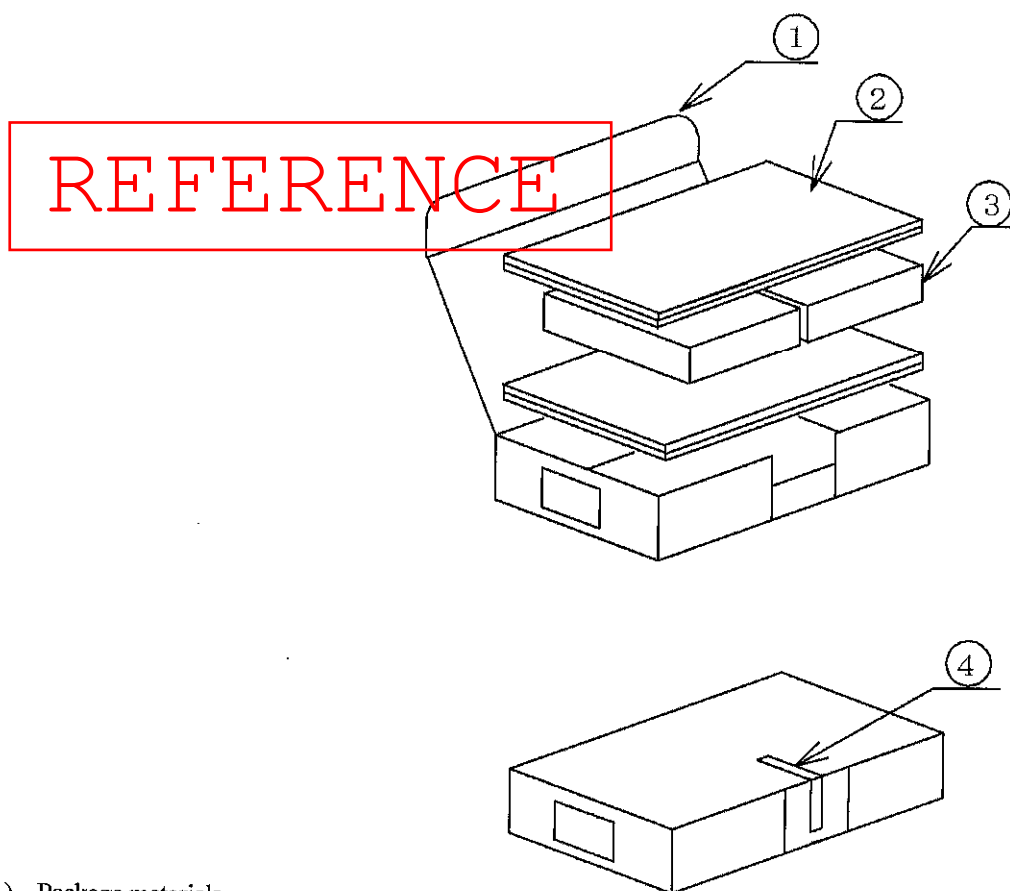
|                           |                       |
|---------------------------|-----------------------|
| Holder                    | Lead flame finish     |
| Black polycarbonate resin | Solder dip (Sn-Ag-Cu) |

## 6.1.4 Others

This product shall not be radiation flux proof.

Laser generator is not used.

## 6.2 Packing (Drawing No.:CY14654i09)



## 1) Package materials

| No | Name                       | Quantity |
|----|----------------------------|----------|
| 1  | Device case                | 1        |
| 2  | Cushioning material        | 4        |
| 3  | Antistatic electricity bag | 2        |
| 4  | Cellophane tape            | -        |

## 2) Packaging numbers

MAX. 50 pieces per bag

MAX. 100 pieces per case

## 3) Indication items

The contents of the carton indication conforms to EIAJ C-3 and the following items are indicated.

Model No., Internal production control name, Quantity, Packing date, Corporate name, Country of origin

## 4) Package specifications

1.Put 50 devices into antistatic electricity bag and seal with cellophane tape.

2.Put two sets of a thing of above 1 to a device case.

In addition,spread two pieces of cushioning material at top and bottom.

3.Seal a device case with cellophane tape.

## 5) Regular packing mass

(Excluding fractions, however above packing material, packing count, packing style)

• Approx. 0.2kg

## Данный компонент на территории Российской Федерации

### Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

### Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: [info@moschip.ru](mailto:info@moschip.ru)

Skype отдела продаж:

moschip.ru

moschip.ru\_4

moschip.ru\_6

moschip.ru\_9